

EAST Search History

EAST Search History (Prior Art)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S75	372	(gan or gallium near2 nitride) near10 (single near2 crystal\$6 or monocystal\$6) and (si or silicon) and compress\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/19 12:24
S74	2605	(gan or gallium near2 nitride) near10 (single near2 crystal\$6 or monocystal\$6) and (si or silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/19 12:24
S73	3533	(gan or gallium near2 nitride) near10 (single near2 crystal\$6 or monocystal\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/19 12:24
S76	9	(gan or gallium near2 nitride) near15 grad\$5 near10 compress\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/19 13:14
S78	110	(gan or gallium near2 nitride) near15 grad\$5 and @py<"2003" and (silicon or si)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/19 13:15
S77	144	(gan or gallium near2 nitride) near15 grad\$5 and @py<"2003"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/19 13:15
S79	75	(gan or gallium near2 nitride) near15 grad\$5 and @py<"2003" and (silicon or si) near5 substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/19 13:16

S80	7	(gan or gallium near2 nitride) near15 grad\$5 near15 (single near2 crystal\$5 or monocrystal\$6) and @py<"2003" and (silicon or si) near5 substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/19 13:19
S81	2	"6765240".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/19 13:21
S82	36	(US-20020036287-\$ or US-20020020341-\$ or US-20040130002-\$ or US-20020028314-\$ or US-20040213309-\$ or US-20080185611-\$ or US-20080102610-\$ or US-20070228395-\$ or US-20070072320-\$ or US-20050054132-\$ or US-20050003571-\$ or US-20030183832-\$ or US-20020110945-\$). did. or (US-5838706-\$ or US-5874747-\$ or US-5679965-\$ or US-5709745-\$ or US-5496767-\$ or US-6120600-\$ or US-3893876-\$ or US-6046464-\$ or US-6611002-\$ or US-6552376-\$ or US-6765240-\$ or US-6281522-\$ or US-6569765-\$ or US-6673149-\$ or US-6177292-\$ or US-7560296-\$ or US-7083996-\$ or US-6861672-\$ or US-6835956-\$ or US-6589808-\$ or US-6534791-\$ or US-5903017-\$).did. or	US-PGPUB; USPAT; DERWENT	OR	ON	2009/07/19 13:32

		(US-5585648-\$).did.				
S85	12	S84 and (si or silicon)	US-PGPUB; USPAT; DERWENT	OR	ON	2009/07/19 13:33
S84	12	S83 and (graded or grading)	US-PGPUB; USPAT; DERWENT	OR	ON	2009/07/19 13:33
S83	29	S82 and (gan or gallium near2 nitride) near15 (single near2 crystal \$5 or monocrystal \$6)	US-PGPUB; USPAT; DERWENT	OR	ON	2009/07/19 13:33
S86	5	(graded or grading) near15 (gan or gallium near2 nitride) near15 (single near2 crystal \$5 or monocrystal \$6)	US-PGPUB; USPAT; DERWENT	OR	ON	2009/07/19 13:37
S87	11	(graded or grading) near15 (gan or gallium near2 nitride or algan or aln or aluminum near2 nitride) near15 (single near2 crystal \$5 or monocrystal \$6)	US-PGPUB; USPAT; DERWENT	OR	ON	2009/07/19 13:38
S89	16	S82 and compress\$5 and (si or silicon) near5 substrate	US-PGPUB; USPAT; DERWENT	OR	ON	2009/07/19 13:40
S88	21	S82 and compress\$5	US-PGPUB; USPAT; DERWENT	OR	ON	2009/07/19 13:40
S90	4	"6765240".pn. "5874747".pn.	US-PGPUB; USPAT; DERWENT	OR	ON	2009/07/19 17:07
S91	1	"5679152".pn. and grad\$5	US-PGPUB; USPAT; DERWENT	OR	ON	2009/07/19 17:17
S92	5	(hugues near2 marchand or brendan near2 moran).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/19 23:17

S97	11	S96 and compress\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/22 11:24
S96	26	(US-20020036287-\$ or US-20020020341-\$ or US-20040130002-\$ or US-20020028314-\$ or US-20040213309-\$ or US-20080185611-\$ or US-20080102610-\$ or US-20070228395-\$ or US-20070072320-\$ or US-20050054132-\$ or US-20050003571-\$ or US-20030183832-\$ or US-20020110945-\$). did. or (US-5838706-\$ or US-5679965-\$ or US-5709745-\$ or US-5496767-\$ or US-6120600-\$ or US-3893876-\$ or US-6046464-\$ or US-6611002-\$ or US-6552376-\$ or US-6765240-\$ or US-6281522-\$ or US-6569765-\$).did. or (US-5585648-\$).did.	US-PGPUB; USPAT; DERWENT	OR	ON	2009/07/22 11:24
S98	18	S96 and grad\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/22 12:42
S101	17	grad\$5 near5 (gallium near2 nitride or gan) and (si) near15 substrate and (gan or gallium near2 nitride) near15 (monocrystal \$6 or single near2 crystal\$5) and @py< "2004"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/22 12:46

S100	97	grad\$5 near5 (gallium near2 nitride or gan) and (si) near15 substrate and (gan or gallium near2 nitride) near15 (monocrystal \$6 or single near2 crystal\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/22 12:46
S99	35	grad\$5 near5 (gallium near2 nitride) and (si) near15 substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/07/22 12:46
S104	12	S103 and compress \$5	US-PGPUB; USPAT; DERWENT	OR	ON	2009/08/03 08:38
S103	27	(US-20020036287-\$ or US-20020020341-\$ or US-20040130002-\$ or US-20020028314-\$ or US-20040213309-\$ or US-20080185611-\$ or US-20080102610-\$ or US-20070228395-\$ or US-20070072320-\$ or US-20050054132-\$ or US-20050003571-\$ or US-20030183832-\$ or US-20020110945-\$). did. or (US-5838706-\$ or US-5874747-\$ or US-5679965-\$ or US-5709745-\$ or US-5496767-\$ or US-6120600-\$ or US-3893876-\$ or US-6046464-\$ or US-6611002-\$ or US-6552376-\$ or US-6765240-\$ or US-6281522-\$ or US-6569765-\$).did. or (US-5585648-\$).did.	US-PGPUB; USPAT; DERWENT	OR	ON	2009/08/03 08:38

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